S1A THRU S1M

SURFACE MOUNT GLASS PASSIVATED SILICON RECTIFIER



REVERSE VOLTAGE: 50 to 1000 VOLTS FORWARD CURRENT: 1.0 AMPERE

FEATURES

· Plastic package has Underwriters Laboratory

Flammability Classification 94V-O

· For surface mounted applications

· Low profile package

· Easy pick and place

· Built-in strain relief

· Low forward voltage drop

· High temperature soldering: 250°C/10 seconds at terminals

MECHANICAL DATA

Case: Molded plastic, DO-214AA(SMB)

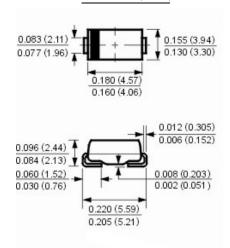
Terminals: Solder plated, solderable per MIL-STD-750,

method 2026 guaranteed

Polarity: Color band denotes cathode end Packaging: 12mm tape per EIA STD RS-481

Weight: 0.003 ounce, 0.093 gram

DO-214AA(SMB)



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

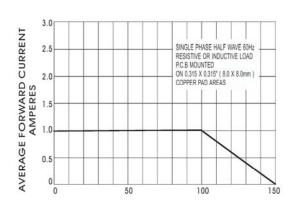
	Symbols	SIA	S1B	SID	S1G	SIJ	S1K	S1M	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T_L =100 $^{\circ}$ C	I _(AV)				1.0				Amp
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I_{FSM}	I _{FSM} 30							Amp
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage at 1.0A	$V_{\rm F}$	1.1							Volts
Maximum Reverse Current at T _A =25℃	T	5.0 100							μАтр
at Rated DC Blocking Voltage $T_A=125$ °C	I_R								
Typical Junction Capacitance (Note 1)	C_{J}	12							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	30							°C/W
Maximum Reverse Recovery Time (Note 3)	T_{RR}	2.5							μS
Operating Junction Temperature Range	T_{J}	-55 to +150							ဇ
Storage Temperature Range	Tstg	-55 to +150							ဗ

NOTES:

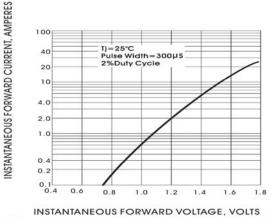
- 1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2- Thermal resistance from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0mm) copper pad areas
- 3- Reverse Recovery Test Conditions: I_F =.5A, I_R =1A, I_{RR} =.25A.



RATINGS AND CHARACTERISTIC CURVES



TEMPERATURE°C
Fig. 1- DERATING CURVE FOR OUTPUT RECTIFIED CURRENT



INSTANTANEOUS FORWARD VOLTAGE, VOLTS
FIG. 2- TYPICAL INSTANTANEOUS FORWARD
CHARACTERISITCS PER ELEMENT

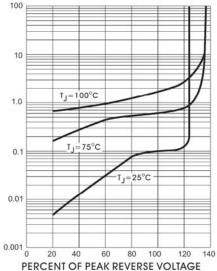


Fig. 3- TYPICAL REAK REVERSE CHARACTERISTICS

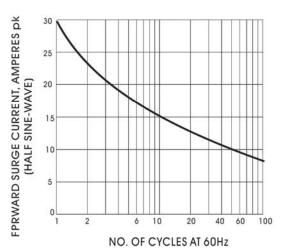


Fig. 4- MAXIMUM NON-REPETITEVE PEAK FORWARD SURGE CURRENT

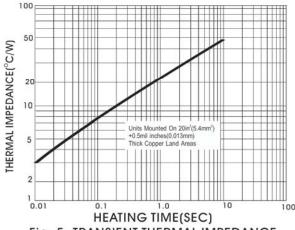


Fig. 5- TRANSIENT THERMAL IMPEDANCE

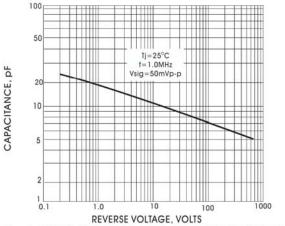


Fig. 6- TYPICL JUNCTION CAPACITANCE PER ELEMENT